GBU6A - GBU6M

Bridge Rectifiers

Features

- Glass-Passivated Junction
- Surge Overload Rating: 175 A Peak
- Reliable Low-Cost Construction Utilizing Molded Plastic Technique
- Ideal for Printed Circuit Board
- UL Certified: UL #E258596

PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Marking	Package	Packing Method
GBU6A	GBU6A	GBU 4L	Rail
GBU6B	GBU6B		
GBU6D	GBU6D		
GBU6G	GBU6G		
GBU6J	GBU6J		
GBU6K	GBU6K		
GBU6M	GBU6M		



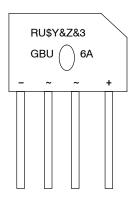
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SIP4 CASE 127EL

MARKING DIAGRAM



RU = UL Marking

\$Y = ON Semiconductor Logo &Z = Assembly Plant Code &3 = Numeric Date Code GBU6A = Specific Device Code

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Publication Order Number: GBU6M/D

GBU6A - GBU6M

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted) (Note 1)

			Value							
Symbol	Parameter		6A	6B	6D	6G	6J	6K	6M	Units
V_{RRM}	Maximum Repetitive Reverse Voltage		50	100	200	400	600	800	1000	V
V_{RMS}	Maximum RMS Bridge Input Voltage	ge	35 70 140 280 420 560 700		700	V				
V_{R}	DC Reverse Voltage (Rated V _R)		50 100 200 400 600 800 1000		1000	V				
I _{F(AV)}	Average Rectified Forward Current	T _A = 100°C	6.0				Α			
I _{FSM}	Non-Repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave			175					Α	
T _{STG}	Storage Temperature Range		-55 to +150					°C		
TJ	Operating Junction Temperature		-55 to +150					°C		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

THERMAL CHARECTERISTICS (T_A = 25°C unless otherwise noted)

Symbol	Parameter	Value	Units
P _D	Power Dissipation	12	W
$R_{ heta JA}$	Thermal Resistance per Leg, Junction to Ambient (Note 2)	18.6	°C/W
$R_{ heta JL}$	Thermal Resistance per Leg, Junction to Lead (Note 3)	3.1	°C/W

^{2.} Device mounted on PCB with 0.5×0.5 inch $(12 \times 12 \text{ mm})$

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Symbol	Parameter	Value	Units	
V _F	Forward Voltage, per Element	6.0 A	1.0	V
I _R	Reverse Current, per Element at Rated V _R	T _A = 25°C	5.0	μΑ
		T _A = 125°C	500	μΑ
I ² t	I ² t Rating for Fusing	t < 8.35 ms	127	A ² s

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

^{3.} Device mounted on Al plate with $2.6 \times 1.4 \times 0.06$ inch $(6.5 \times 3.5 \times 0.15$ cm)

GBU6A - GBU6M

TYPICAL PERFORMANCE CHARACTERISTICS

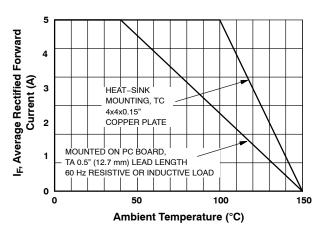


Figure 1. Forward Current Derating Curve

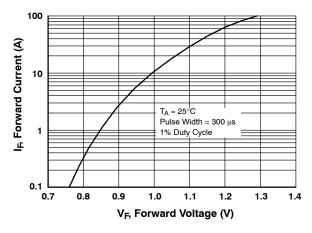


Figure 2. Forward Voltage Characteristics

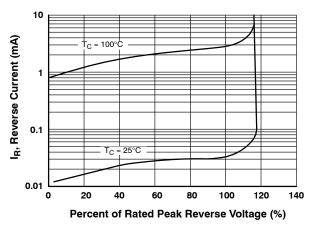


Figure 3. Reverse Current vs. Reverse Voltage

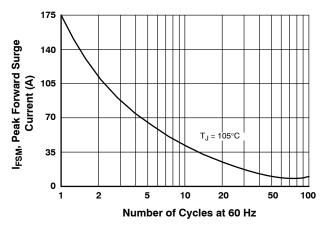
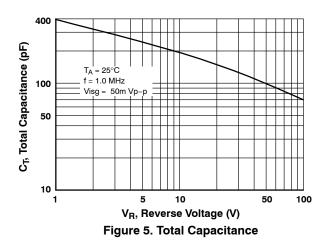
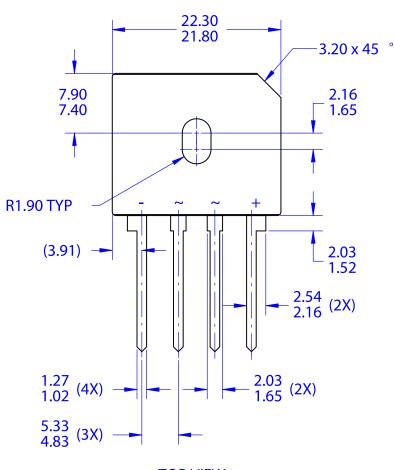


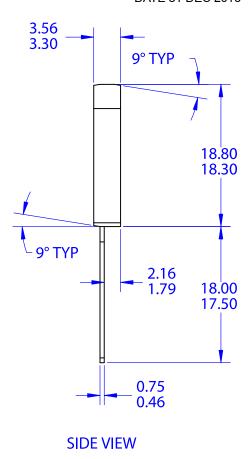
Figure 4. Non-Repetitive Surge Current



SIP4 22.05x18.55 CASE 127EL ISSUE O

DATE 31 DEC 2016





TOP VIEW

NOTES:

- A. NO INDUSTRY STANDARD APPLIES TO THIS PACKAGE
- **B. ALL DIMENSIONS ARE IN MILLIMETERS**
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
- D. DIMENSIONS AND TOLERANCES AS PER ASME Y14.5-2009

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